TIP36C

Rev.E Mar.-2016

DATA SHEET

/ Descriptions

WR06S ṂṂ Ƀ SQS ÆṀ ч s ǁ ㄱ Silicon PNP transistor in a TO-3P Plastic Package.

/ Features

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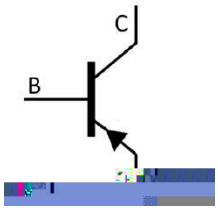
Low leakage current, high current gain bandwidth product, Complementary to TIP35C.

/ Applications

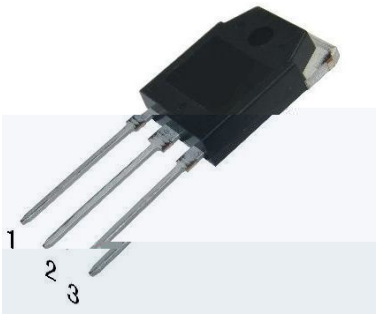
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Amplifier and switching applications.

/ Equivalent Circuit



/ Pinning



PIN1 χ Base PIN 2 χ Collector PIN 3 χ Emitter

/ h_{FE} Classifications & Marking

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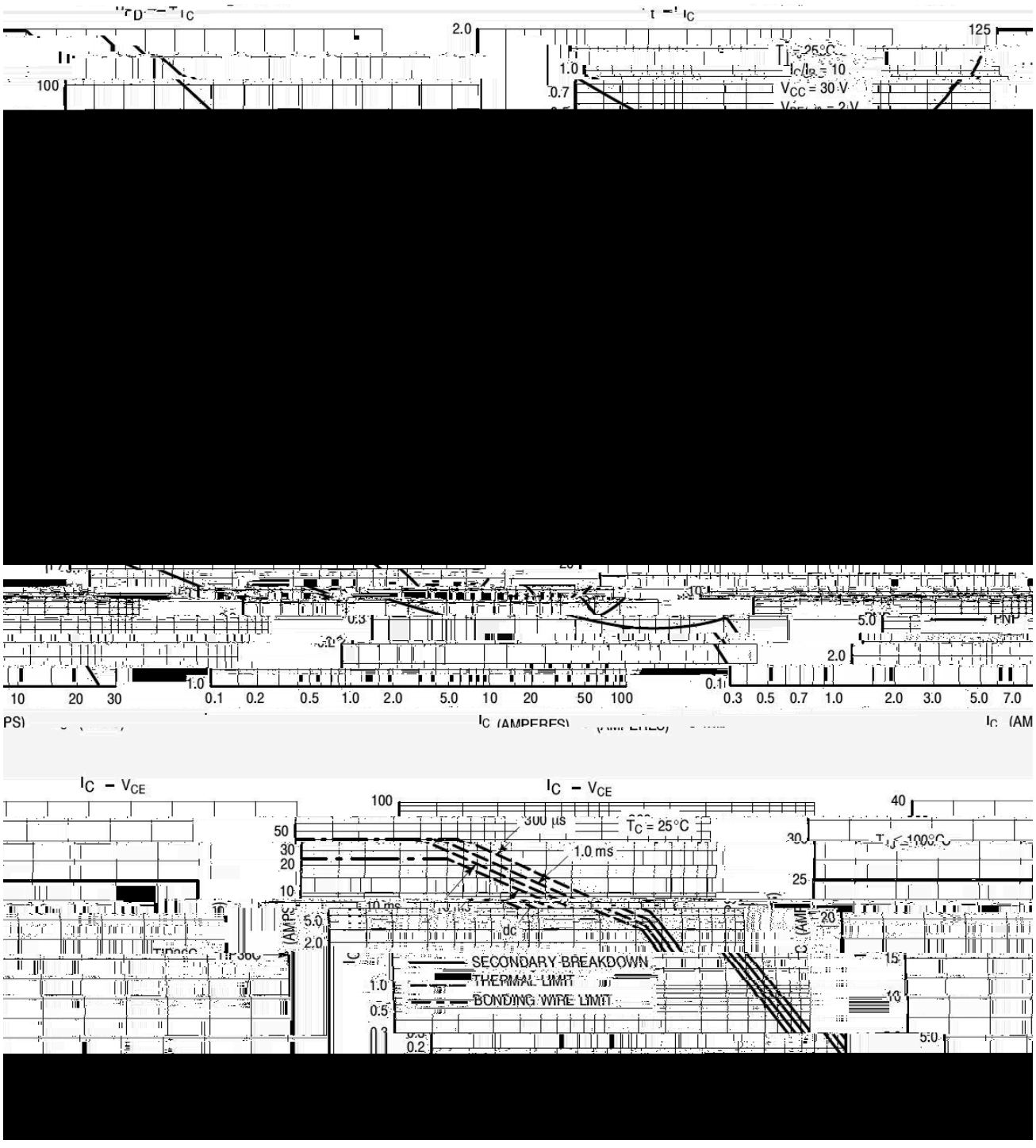
v ¨Q Parameter	ϒ N Symbol	¨Q Ö Rating	D Ч Unit
Collector to Base Voltage	V_{CBO}	-100	V
Collector to Emitter Voltage	V_{CEO}	-100	V
Emitter to Base Voltage	V_{EBO}	-5	V
Collector Current - Continuous	I_C	-25	A
Peak Collector Current	I_{CM}	-50	A
Base Current	I_B	-5	A
Total Power Dissipation	P_{tot}	125	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-65 150	
Thermal Resistance Junction	R_{thj}	1	/W

Collet(orto EmiteterBrea)7.4(kdownA)]TJETq1 i 56.01 178.18 34074711642 reW* nBT10.5 0 0 10.5 55.98 19.42003 T

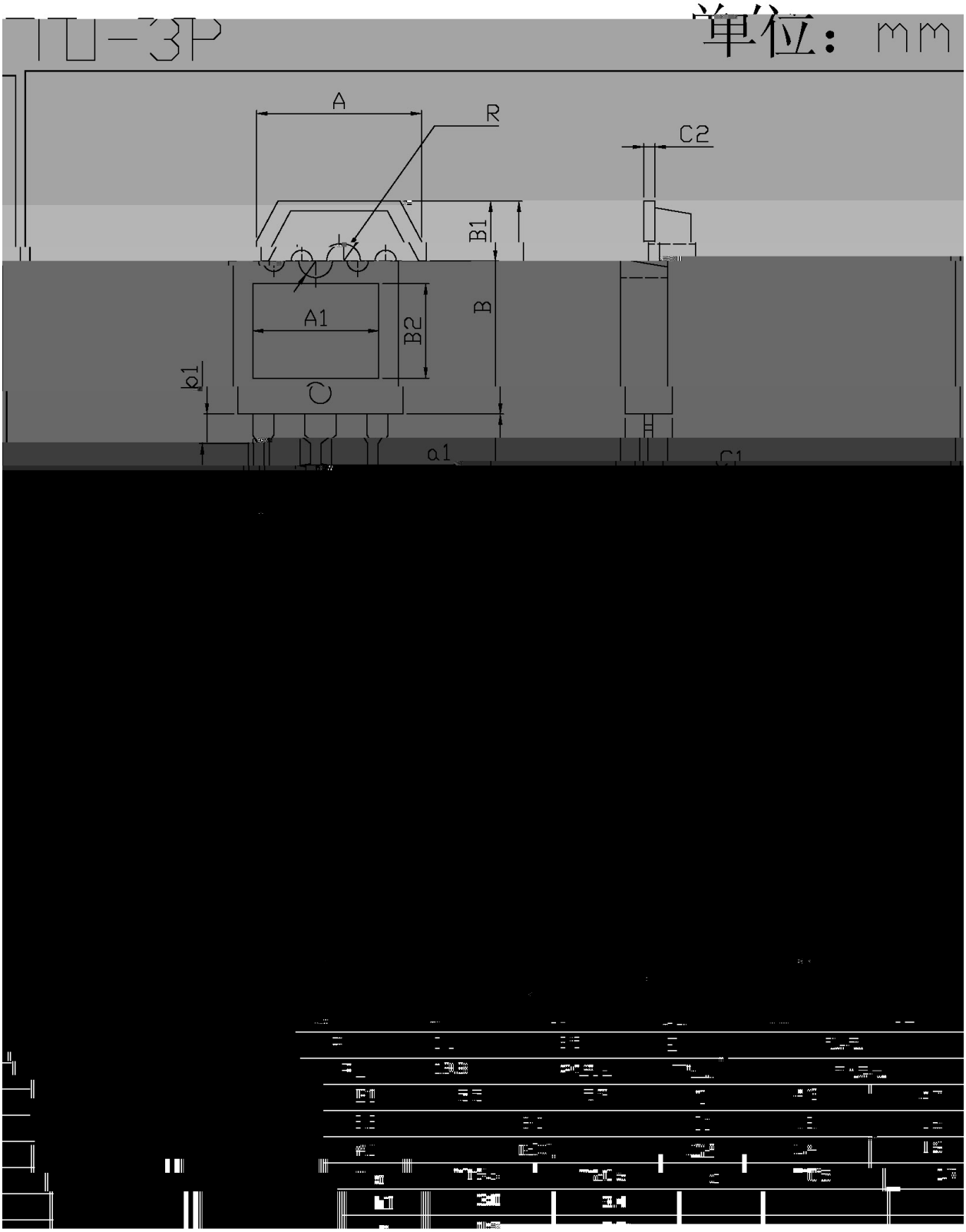
v ¨Q Parameter	ϒ N Symbol	Ш :¦ Ţ Test Conditions	ώ ņ Ö Min	Ε ʒ Ö Typ	ώ ² Ö Max	D Ч Unit
Collector Cut-Off Current	I_{CEO}	V_{CE}=-60V I_B=0			-1	mA
Collector Cut-Off Current	I_{CES}	V_{CE}=-60V V_{BE}=0			23a	

f-Curren( )73531.4(I)]TJ7.02 0 0 7.02 2460543425.4004 Tm-0.0003 Tc0 TwEBO

/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



EU:	
WLS69F	

Note:

BR:	Company Code.
TIP36C:	Product Type.
****:	Lot No. Code, code change with Lot No.